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Supplementary Materials for

One-step vapor-phase synthesis of transparent high refractive index sulfur-containing polymers

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Supplementary Text

X-ray reflectometry (XRR) analysis

The analysis method involves measuring the intensity of X-ray beam reflected on the sample with changing the incident angle of X-ray. In the XRR analysis, the refractive index of material can be estimated by the equation (1). When the incident angle is lower than the critical angle, incident X-ray beam is totally reflected and thus the reflectivity value becomes 1. Therefore, the critical angle is related to the refractive index of material, which can be calculated by the following equations *(38)*.

$$n = 1 - \delta - i\beta \tag{1}$$

$$\delta = \left(\frac{r_e \lambda^2}{2\pi}\right) N_o \rho \sum_i x_i (Z_i + f_i') / \sum_i x_i M_i \qquad (2)$$

$$\beta = \left(\frac{r_e \lambda^2}{2\pi}\right) N_o \rho \sum_i x_i (Z_i + f_i'') / \sum_i x_i M_i \qquad (3)$$

 r_e : Classical radius of an electron (2.818×10⁻⁹ m); N_o : Avogadro number;

 λ : X-ray wavelength; ρ : Density (g/cm³); Z_i : Atomic number of the ith atom;

 M_i : Atomic weight of the ith atom; x_i : Atomic ratio of the ith atom;

 f_i', f_i'' : Atomic scattering factor of the ith atom

where δ is the energy dispersive term, and β is X-ray absorption term.

The real part of the complex refractive index is related to the phase velocity of X-ray in the material, and the imaginary part is related to the X-ray absorption of the material. Therefore, the critical angle is related only to the real part of the complex refractive index, which can be calculated as follows.

$$n = 1 - \delta = \cos(\theta_c) = 1 - \frac{\theta_c^2}{2} \qquad (4)$$
$$\theta_c = \sqrt{2\delta} \qquad (5)$$

Since the δ value includes the density information of the sample, which can be calculated from the critical angle value of the incident X-ray beam. In our data, the critical angle is 0.35°, which gives the density of SBDDDVE as 1.58 g/cm³.

Conformal coating on complex structure

In the EDS spectra from the cross-sectional images in **Fig. S2**, bare stainless steel mesh shows only a trace amount of sulfur, while the stainless steel mesh coated with 200 nm-thick SBDDVE shows 9.43 wt% sulfur content at the side of the mesh fiber, which indicates deposition of SCP is accomplished.



Fig. S1. SCP films on various substrates. Digital camera images of the colorless poly(sulfurco-1,4-butanediol divinyl ether) (SBDDVE) films (thickness = 110 nm), deposited on (A) glass,
(B) silicon wafer, (C) polyethylene terephthalate (PET), (D) polyethylene naphthalate (PEN), (E) polyimide (PI), (F) polydimethyl siloxane (PDMS), and (G) latex. (Scale bar : 1cm) Photo credit: Wontae Jang (Korea Advanced Institute of Science and Technology).



Fig. S2. Cross-sectional scanning electron microscope (SEM) image and energy dispersive spectroscopy (EDS) scan spectra with sulfur atom peaks (red dash line) of the stainless steel mesh coated with the sulfur-containing polymer (SCP) film (Spectrum 1) and the non-coated area (Spectrum 2) of (**A**) before and (**B**) after the 200 nm SBDDVE film deposition on the stainless steel mesh.



Fig. S3. X-ray diffraction (XRD) spectra of (**A**) SBDDVE film with 61.64 wt% and (**B**) 66.82 wt% of sulfur contents; (**C**) SV4D4, (**D**) SV3D3, (**E**) SHVDS, deposited by sCVD, and **Fourier transform infrared (FTIR) spectra** of (**F**) 1, 4-butanediol divinyl ether (BDDVE), di(ethylene glycol)divinyl ether (DEGDVE), 1,11-dodecadiene (DDDE), 1,9-decadiene(DDE), and the SCPs of poly(sulfur-co-1,4-butanediol divinyl ether) (SBDDVE), poly(sulfur-co-di(ethylene glycol)divinyl ether) (SDEGDVE), poly(sulfur-co-1,11-dodecadiene) (SDDDE), poly(sulfur-co-1,9-decadiene) (SDDE) synthesized by sCVD, (**G**) 1,3,5-trivinyl-1,3,5-trimethylcyclotetrasiloxane

(V4D4), hexavinyldisiloxane (HVDS) monomer, and their corresponding polymers of poly(1,3,5-trivinyl-1,3,5-trimethylcyclotrisiloxane) (pV3D3), poly(1,3,5,7-tetravinyl-1,3,5,7-tetramethyl cyclotetrasiloxane) (pV4D4), poly(hexavinyldisiloxane) (pHVDS), and the SCPs of poly(sulfur-co-di(ethylene glycol)divinyl ether) (SDEGDVE), poly(sulfur-co-1,3,5-trivinyl-1,3,5-trimethylcyclotrisiloxane) (SV3D3), poly(sulfur-co-1,3,5,7-tetravinyl-1,3,5,7-tetramethylcyclotetrasiloxane) (SV4D4), and poly(sulfur-co-hexavinyldisiloxane) (SHVDS), synthesized by sCVD, where blue area at 1100, 2900 cm⁻¹ represent -C-O-C- and -C-H stretching peaks, respectively, and gray area at 1260 cm⁻¹ represents Si-CH₃ peak.



Fig. S4. UV-Vis absorbance (**A**) and normalized UV-Vis absorbance (**B**) spectra of SBDDVE films of varying thickness obtained from sCVD, and the refractive index (n) and extinction coefficient (k) values of (**C**) SV3D3, (**D**) SV4D4, (**E**) SDDDE, (**F**)SDDE obtained by ellipsometry measurement.



Fig. S5. Thickness variation of SBDDVE film with respect to (**A**) substrate temperatur (T_s) (**B**) the sulfur loading amount (with the fixed chamber pressure of 1000 mTorr and substrate temperature (T_s) = 110 °C), (**C**) the chamber pressure (with the fixed sulfur amount 0.1 g and T_s = 110 °C), (**D**) Thickness, (**E**) refractive index variation of SBDDVE film with respect to sulfur loading amount (with the fixed chamber pressure of 1000 mTorr and T_s = 110 °C) with 120 min reaction time, (**F**) thickness, (**G**) refractive index variation of the substrate temperature (with the fixed sulfur loading amount of 0.3 g and the process pressure of 1000 mTorr).



Fig. S6. X-ray photoelectron spectroscopy (XPS) survey spectra and deconvoluted S2p (left), C1s (center), O1s (right) XPS high resolution scan spectra of SBDDVE films with various sulfur contents of (A) 71.90 wt%, (B) 68.82 wt%, (C) 66.86 wt%, (D) 63.58 wt%, and (E) 61.69 wt%. Deconvoluted spectra are colored with light blue for S-C-O, green for C-O, blue for C-S, and grey for C-C in C1s XPS high resolution spectra, blue for C-S and red for S-S, respectively, in S2p XPS high resolution spectra, and green as C-O in O1s XPS high resolution spectra.

	Material	N 632.8nm	Color	Notes	Ref
Poly(SDIB). Copolymer +S-s-S-s-S-s-S-s-S-s-S-s-S-s-S-s-S-s-S-s		1.87	Yellow/ Red	 Synthesized by inverse vulcanization Must use olefin monomer miscible with elemental sulfur A strong absorption in visible region Hard to mold into thin film due to the la ck of solubility in common organic solve nts. 	1
oly(S-r-TIB) Poly (S-r-TIB) Poly oly(S-r-TIB)	Pol	1.83	Orange/ Red	 Synthesized by inverse vulcanization Use of sulfur and olefin comonomer wit h tri-vinyl groups A strong absorption in visible region 	6
		1.78	Yellow	 Multi-step synthesis. Tellurium was used to maximize the ref ractive index. A strong absorption in visible region 	39
H S C P	This study	> 1.90	Colorless	 One-step sCVD in vapor phase. No limit in monomer selection. Fully transparent in whole visible region. Film thickness and refractive index proper can be controlled in systematic manner. Extremely high refractive index larger that 	erties In 1.9.

Table S1. Comparison of SCPs from sCVD with those synthesized by other methods. Tristan S. Kleine (University of Arizona) and Wontae Jang (Korea Advanced Institute of Science and Technology).

Table S2. Refractive index from ellipsometry measurement, and calculated Abbe's number (v_D) of the SBDDVE films with two different refractive index, SDDDE, SDDE, SV3D3, and SV4D4 synthesized by sCVD.

Polymer	N 632.8	N656.3	N 589.3	N 486.1	VD
SBDDVE -	1.915	1.910	1.926	1.973	14.698
	1.726	1.724	1.732	1.755	23.613
SDDDE	1.719	1.717	1.725	1.748	23.387
SDDE	1.754	1.751	1.760	1.787	21.111
SV3D3	1.729	1.726	1.737	1.767	17.976
SV4D4	1.708	1.706	1.714	1.738	22.313

Table S3. XPS survey scan quantitative result of SBDDVE films with various sulfur weight %(wt%), copolymer ratio, and S-S/S-C bond ratio.

Sulfur wt%	Atomic %			Copolymer ratio	S-S/S-C ratio
	S	С	0	S ₈ : BDDVE	_
71.90	52.81	37.24	9.95	1.42 : 1	1.84
68.82	48.48	39.63	11.88	1.22 : 1	1.45
66.86	46.21	41.31	12.49	1.12 : 1	1.24
63.58	43.23	44.68	12.09	0.97 : 1	0.94
61.69	41.46	46.44	12.09	0.89 : 1	0.79

 * Considered Molecular weight of S $_{_{8}}$ is 256.52, and BDDVE is 142.2

Sulfur wt%	S	2p deconvol	S-C bond ratio in total	S-S/S-C		
	C-S 2p _{1/2}	C-S 2p _{3/2}	S-S 2p _{1/2}	S-S 2p _{3/2}	polymer (%)	
71.90	8323.85	16647.69	16324.03	32648.06	17.83	1.96
68.82	13192.70	26385.40	18700.00	37400.00	20.05	1.42
66.86	13628.79	27257.58	18591.42	37182.83	19.54	1.36
63.58	15622.28	31244.56	14174.77	28349.55	22.66	0.91
61.69	16201.22	32402.44	12762.19	25524.38	23.19	0.79

Table S4. XPS S2p, C1s high resolution scan quantitative result of SBDDVE films with various sulfur weight % (wt%), calculated S-C bond ration in total polymer, and S-S/S-C bond ratio

Sulfur wt%	C*	S-C bond ratio in total				
	S-C-0	0 C-0 C-S		C-C	polymer (%)	
71.90	7341.494	7381.83	7229.488	7255.087	18.58	
68.82	12404.24	11721.76	12283.53	12036.01	20.20	
66.86	12631.49	13623.93	13757.76	13140.88	20.51	
63.58	14222.58	13890.16	13877.22	13602.36	22.58	
61.69	13843.02	14036.51	14196.76	14008	23.22	

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